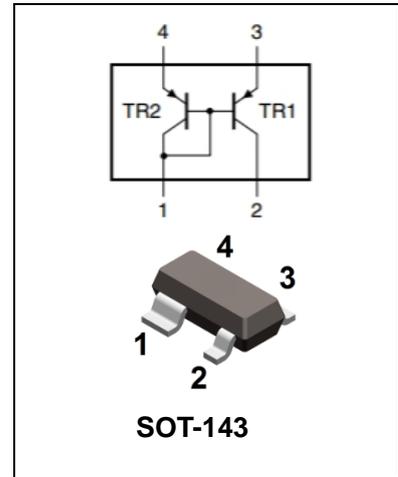


Features

- Low current
- Low voltage
- Matched pairs
- Compliant to Halogen-free

Mechanical Data

- Case: SOT-143
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208
- Marking Code : AD



Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _C	-100	mA
Peak Collector Current	I _{CM}	-200	mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation (T _A = 25°C) *1	P _D	390	mW
Thermal Resistance Junction-to-Air *1	R _{θJA}	320	°C/W
Thermal Resistance Junction-to-Case *1	R _{θJC}	230	°C/W
Thermal Resistance Junction-to-Lead *1	R _{θJL}	250	°C/W
Operating Junction Temperature	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Note 1: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$	-50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}, I_C = 0$	-5	-	-	V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -30\text{V}, I_E = 0$	-	-	-15	nA
Emitter Cut-Off Current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$	-	-	-100	nA
DC Current Gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -100\mu\text{A}$	100	-	-	-
		$V_{CE} = -5\text{V}, I_C = -2\text{mA}$	200	-	450	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$	-	-	-0.2	V
		$I_C = -100\text{mA}, I_B = -5\text{mA}$	-	-	-0.4	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$	-	-0.71	-	V
		$I_C = -100\text{mA}, I_B = -5\text{mA}$	-	-0.85	-	V
Base-Emitter Turn-on Voltage	$V_{BE(on)}$	$I_C = -2\text{mA}, V_{CE} = -5\text{V}$	-0.6	-	-0.7	V
		$I_C = -10\text{mA}, V_{CE} = -5\text{V}$	-	-	-0.76	V
Transition Frequency	f_T	$V_{CE} = -5\text{V}, I_C = -10\text{mA},$ $f = 100\text{MHz}$	100	-	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0$ $f = 1\text{MHz}$	-	-	2.2	pF

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

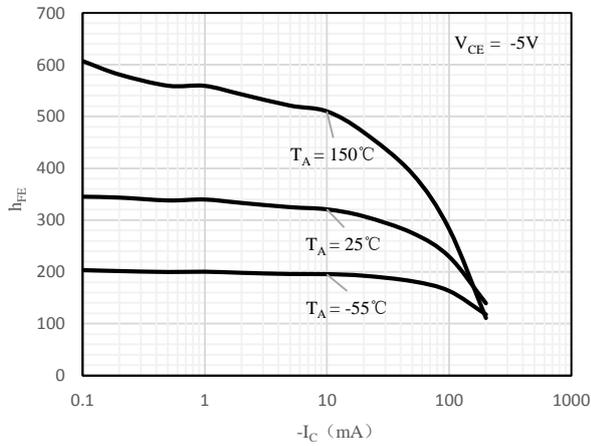


Fig 1 h_{FE} vs. I_c

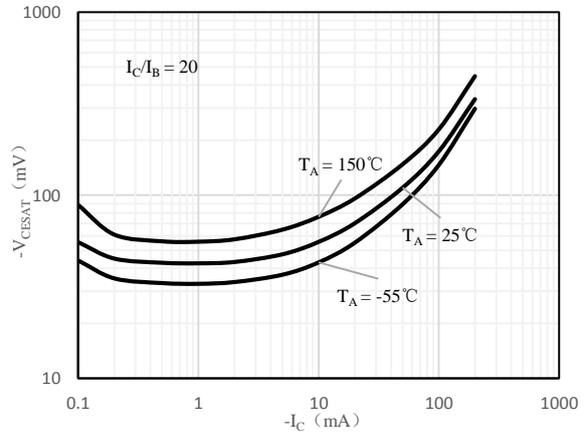


Fig 2 $V_{CE(sat)}$ vs. I_c

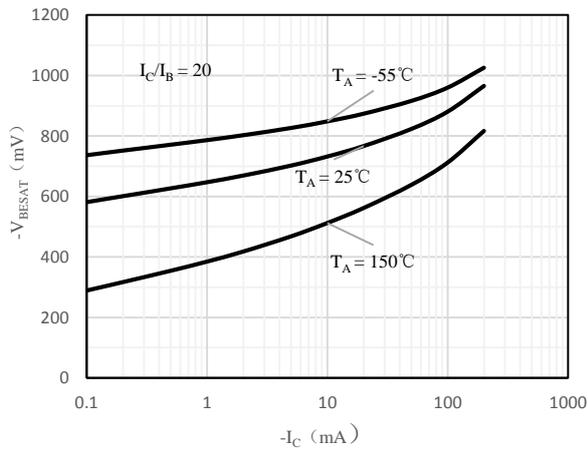


Fig 3 $V_{BE(sat)}$ vs. I_c

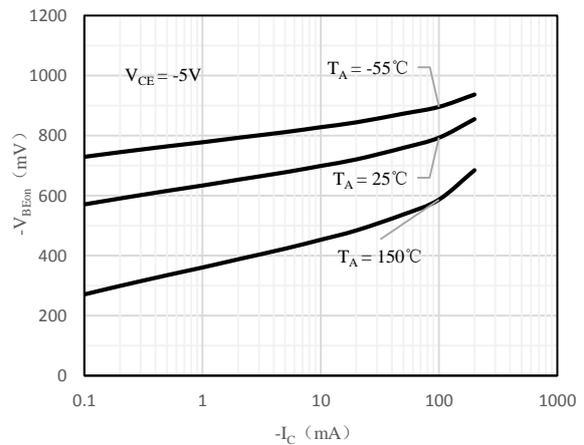
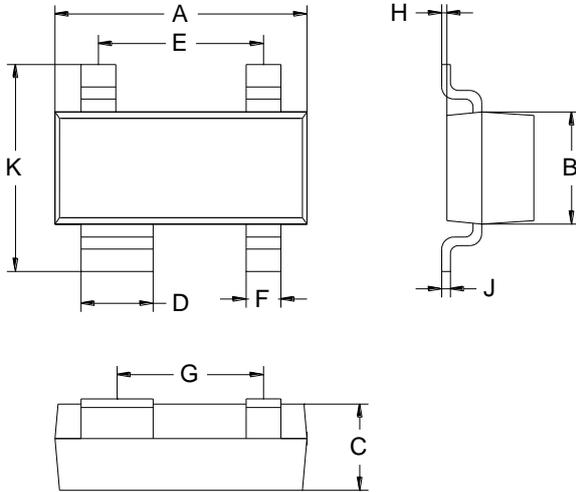


Fig 4 $V_{BE(ON)}$ vs. I_c

Package Outline Dimensions (Unit: mm)



SOT-143		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.90	1.10
D	0.78	0.88
E	1.80	2.00
F	0.37	0.43
G	1.59	1.79
H	0.02	0.10
J	0.05	0.15
K	2.20	2.60

Package Outline Dimensions (Unit: mm)

SOT-143

